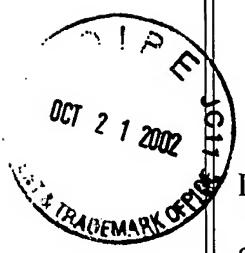


IN THE UNITED STATES PATENT AND TRADEMARK OFFICE



2811
#7121
10/24/02
PENT
TECHNOLOGY CENTER 2800
OCT 23 2002
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In re Appln. Of: MAYUZUMI

Serial No.: 10/036,955 ✓

Filed: December 20, 2001

For: SEMICONDUCTOR DEVICE AND METHOD OF ...

Group: 2811

Examiner: IM, JUNGHWAN M.

DOCKET: NEC 01FN061

Assistant Commissioner of Patents
Washington, D.C. 20231

AMENDMENT B

Dear Sir:

This Amendment is being filed in response to the Official Action mailed
August 14, 2002.

Please amend the Application as follows:

IN THE CLAIMS:

Please amend claims 1, 2, 3, 7, 8, 9, 11, 12 and 13 to read as follows:

1. (Amended) A semiconductor device comprising:
a semiconductor substrate;
a gate insulation film formed on said semiconductor substrate;
a gate electrode formed on said gate insulation film and having a portion increasing
upward in the length along a gate length direction, said gate electrode further having a visor
portion;

A1 Sub B1

HAYES SOLOWAY P.C.
130 W. CUSHING ST.
TUCSON, AZ 85701
TEL. 520.882.7623
FAX. 520.882.7643

175 CANAL STREET
MANCHESTER, NH 03101
TEL. 603.668.1400
FAX. 603.668.8567